

MCP73123/223

Lithium Iron Phosphate (LiFePO₄) Battery Charge Management Controller with Input Overvoltage Protection

Features:

- Complete Linear Charge Management Controller:
 - Integrated Input Overvoltage Protection (OVP)
 - Integrated Pass Transistor
 - Integrated Current Sense
 - Integrated Reverse Discharge Protection
- Constant Current/Constant Voltage Operation with Thermal Regulation
- 4.15V Undervoltage Lockout (UVLO)
- 18V Absolute Maximum Input with OVP:
 - 6.5V MCP73123
 - 13V MCP73223
- High Accuracy Preset Voltage Regulation Through Full Temperature Range (-5°C to +55°C):
 - +0.5% MCP73123
 - ±0.6% MCP73223
- Battery Charge Voltage Options:
 - 3.6V MCP73123
 - 7.2V MCP73223
- Resistor Programmable Fast Charge Current:
 - 130 mA 1100 mA
- · Preconditioning of Deeply Depleted Cells:
 - Available Options: 10% or Disable
- Integrated Precondition Timer:
 - 32 Minutes or Disable
- Automatic End-of-Charge Control:
 - Selectable Minimum Current Ratio: 5%, 7.5%, 10% or 20%
 - Elapse Safety Timer: 4 HR, 6 HR, 8 HR or Disable
- Automatic Recharge:
 - Available Options: 95% or Disable
- Factory Preset Charge Status Output:
 - On/Off or Flashing
- Soft Start
- Temperature Range: -40°C to +85°C
- Packaging: DFN-10 (3 mm x 3 mm)

Applications:

- Low-Cost LiFePO₄ Battery Chargers
- Power Tools
- Toys
- · Backup Energy Storage Solutions

Description:

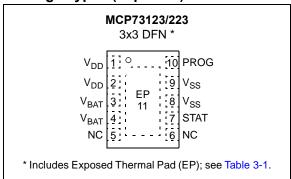
The MCP73123/223 is a highly integrated Lithium Iron Phosphate (LiFePO₄) battery charge management controller for use in space-limited and cost-sensitive applications. The MCP73123/223 provides specific charge algorithms for LiFePO₄ batteries to achieve optimal capacity and safety in the shortest charging time possible. Along with its small physical size, the low number of external components makes the ideally MCP73123/223 suitable for applications. The absolute maximum voltage, up to 18V, allows the use of MCP73123/223 in harsh environments, such as low cost AC adapter or voltage spikes from plugging/unplugging.

The MCP73123/223 employs a constant current/constant voltage charge algorithm. The 3.6V per cell factory preset reference voltage simplifies design with 2V preconditioning threshold. The fast charge, constant current value is set with one external resistor from 130 mA to 1100 mA. The MCP73123/223 also limits the charge current based on die temperature during high power or high ambient conditions. This thermal regulation optimizes the charge cycle time while maintaining device reliability.

The PROG pin of the MCP73123/223 also serves as the enable pin. When high impedance is applied, the MCP73123/223 will be in Standby mode.

The MCP73123/223 is fully specified over the ambient temperature range of -40°C to +85°C. The MCP73123/223 is available in a 10 lead DFN package.

Package Types (Top View)



Typical Application

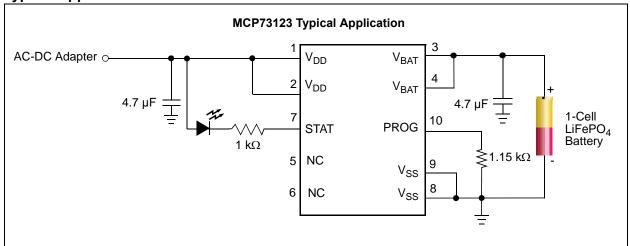


TABLE 1: AVAILABLE FACTORY PRESET OPTIONS

Charge Voltage	OVP	Preconditioning Charge Current	Preconditioning Threshold	Precondition Timer	Elapse Timer	End-of- Charge Control	Automatic Recharge	Output Status
3.6V	6.5V	Disable/10%	2V	Disable / 32 Minimum	Disable/4 hr./ 6 hr./8 hr.	5%/7.5%/ 10%/20%	No / Yes	Type 1/ Type 2
7.2V	13V	Disable/10%	4V	Disable / 32 Minimum	Disable/4 hr./ 6 hr./8 hr.	5%/7.5%/ 10%/20%	No / Yes	Type 1/ Type 2

- Note 1: I_{REG} : Regulated fast charge current.
 - 2: V_{REG} : Regulated charge voltage.
 - 3: I_{PREG}/I_{REG}: Preconditioning charge current; ratio of regulated fast charge current.
 - 4: I_{TERM}/I_{REG}: End-of-Charge control; ratio of regulated fast charge current.
 - **5:** V_{RTH}/V_{REG}: Recharge threshold; ratio of regulated battery voltage, 0% or 95%. 0% = Disabled.
 - **6:** V_{PTH}/V_{REG}: Preconditioning threshold voltage.
 - 7: Type 1: On/Off; Type 2: Flashing. Please refer to Table 5-2.

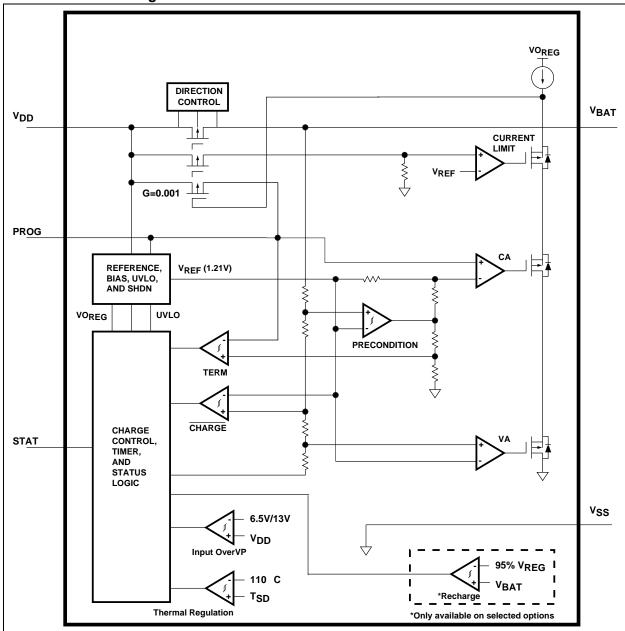
TABLE 2: STANDARD SAMPLE OPTIONS

Part Number	V _{REG}	OVP	I _{PREG} /I _{REG}	Precharge Timer	Elapse Timer	I _{TERM} /I _{REG}	Auto Recharge Threshold (0% = Disabled)	V _{PTH} /V _{REG}	Output Status
MCP73123-22S/MF	3.6V	6.5V	10%	32 Min.	6 hr.	10%	95%	2V	Type 1
MCP73123-22A/MF	3.6V	6.5V	10%	32 Min.	6 hr.	10%	0%	2V	Type 1
MCP73223-C2S/MF	7.2V	13V	10%	32 Min.	6 hr.	10%	95%	4V	Type 1
MCP73223-C2A/MF	7.2V	13V	10%	32 Min.	6 hr.	10%	0%	4V	Type 1

- Note 1: Customers should contact their distributor, representatives or field application engineer (FAE) for support and samples.

 Local sales offices are also available to help customers. A listing of sales offices and locations is included in the back of this document. Technical support is available through the web site at: http://support.microchip.com.
 - 2: Contact your local Microchip sales office for alternative device options.

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

V _{DD} 18.0	V
V _{PROG} 6.0	V
All Inputs and Outputs w.r.t. V _{SS} 0.3 to (V _{DD} +0.3)	٧
Maximum Junction Temperature, T _J Internally Limite	d
Storage temperature65°C to +150°	С
ESD protection on all pins	
Human Body Model (1.5 kΩ in Series with 100 pF)≥ 4 k	١V
Machine Model (200nF, No Series Resistance) 300	۱\/

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: $L_A = -40$ °C to +85°C. Typical	Jnless otherwise values are at +2	indicated, all 25°C, V _{DD} = [limits apply fo V _{REG} (Typical)	r V _{DD} = [V _{REG} (+ 1.0V]	Typical) +	- 0.3V] to 12V,
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Supply Input						
Input Voltage Range	V_{DD}	4	_	16	V	
Operating Supply Voltage	V_{DD}	4.2	_	6.5	V	MCP73123
Operating Supply Voltage	V_{DD}	4.2	_	13.0	V	MCP73223
Supply Current	I _{SS}	_	4	5.5	μA	Shutdown ($V_{DD} \le V_{BAT}$ - 150 mV)
		_	700	1500	μA	Charging
		_	30	100	μΑ	Standby (PROG Floating)
		_	50	150	μA	Charge Complete; No Battery; V _{DD} < V _{STOP}
Battery Discharge Current						
Output Reverse Leakage	I _{DISCHARGE}	_	0.5	2	μA	Standby (PROG Floating)
Current		_	0.5	2	μA	Shutdown ($V_{DD} \le V_{BAT}$, or $V_{DD} < V_{STOP}$)
		_	6	17	μΑ	Charge Complete; V _{DD} is present
Undervoltage Lockout						
UVLO Start Threshold	V _{START}	4.10	4.15	4.25	V	
UVLO Stop Threshold	V_{STOP}	4.00	4.05	4.15	V	
UVLO Hysteresis	V_{HYS}	_	100	_	mV	
Overvoltage Protection						
OVP Start Threshold	V _{OVP}	6.4	6.5	6.6	V	MCP73123
OVP Start Threshold	V _{OVP}	12.8	13	13.2	V	MCP73223
OVP Hysteresis	V _{OVPHYS}	_	150	_	mV	
Voltage Regulation (Const	ant Voltage Mod	ie)				
Regulated Output Voltage	V_{REG}	3.582	3.60	3.618	V	T_A = -5°C to +55°C, I_{OUT} = 50 mA - MCP73123
Output Voltage Tolerance	V _{RTOL}	-0.5	_	+0.5	%	T _A = -5°C to +55°C - MCP73123
Regulated Output Voltage	V _{REG}	7.157	7.20	7.243	V	T_A = -5°C to +55°C, I_{OUT} = 50 mA - MCP73223
Output Voltage Tolerance	V _{RTOL}	-0.6	_	+0.6	%	T _A = -5°C to +55°C - MCP73223

Note 1: Not production tested. Ensured by design.

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise indicated, all limits apply for V_{DD} = [V_{REG} (Typical) + 0.3V] to 12V, $T_A = -40$ °C to +85°C. Typical values are at +25°C, $V_{DD} = [V_{REG} \text{ (Typical)} + 1.0V]$ Units Conditions **Parameters** Sym. Min. Тур. Max. 0.05 0.20 $V_{DD} = [V_{REG}(Typical)+1V]$ to 6V Line Regulation $|(\Delta V_{BAT}/$ - MCP73123 $V_{BAT})/\Delta V_{DD}$ $V_{DD} = [V_{REG}(Typical)+1V]$ to 12V - MCP73223 $I_{OUT} = 50 \text{ mA}$ Load Regulation $|\Delta V_{BAT}/V_{BAT}|$ 0.05 0.20 $I_{OUT} = 50 \text{ mA} - 150 \text{ mA}$ $V_{DD} = [V_{REG}(Typical)+1V]$ Supply Ripple Attenuation **PSRR** dB I_{OUT} = 20 mA, 10 Hz to 1 kHz -46 -30 dΒ $I_{OUT} = 20 \text{ mA}, 10 \text{ Hz to } 10 \text{ kHz}$ **Battery Short Protection BSP Start Threshold** ٧ MCP73123 **V_{SHORT}** 1.45 **BSP Start Threshold** V MCP73223 V_{SHORT} 2.90 **BSP** Hysteresis 150 mV V_{BSPHYS} **BSP Regulation Current** 25 mA I_{SHORT} **Current Regulation (Fast Charge, Constant-Current Mode)** Fast Charge Current 1100 $T_A=-5$ °C to +55°C 130 mΑ IREG Regulation PROG = $10 \text{ k}\Omega$ 130 mΑ PROG = 1.1 $k\Omega$ 1000 mΑ Preconditioning Current Regulation (Trickle Charge Constant Current Mode) Precondition Current Ratio % PROG = 1 $k\Omega$ to 10 $k\Omega$ 10 I_{PREG}/I_{REG} $T_A=-5$ °C to +55°C 100 % No Preconditioning Precondition Voltage ٧ V_{PTH} 1.9 2.0 2.1 MCP73123, V_{BAT} Low-to-High Threshold Ratio V_{PTH} ٧ 4.0 MCP73223, V_{BAT} Low-to-High 3.8 4.2 Precondition Hysteresis V_{PHYS} 100 m۷ V_{BAT} High-to-Low (Note 1) **Charge Termination Charge Termination** 3.7 5 6.3 PROG = 1 k Ω to 10 k Ω I_{TERM}/I_{REG} **Current Ratio** $T_A=-5$ °C to +55°C 5.6 7.5 9.4 7.5 10 12.5 15 20 25 **Automatic Recharge** Recharge Voltage 93 95 97 V_{BAT} High-to-Low V_{RTH}/V_{REG} Threshold Ratio No Automatic Recharge 0 **Pass Transistor ON-Resistance ON-Resistance** 350 $\mathsf{m}\Omega$ $V_{DD} = 4.5V, T_{J} = 105^{\circ}C \text{ (Note 1)}$ **R**DSON Status Indicator - STAT Sink Current I_{SINK} 20 35 mΑ ٧ Low Output Voltage 0.5 V_{OL} 0.2 $I_{SINK} = 4 \text{ mA}$ High Impedance, $V_{\mbox{\scriptsize DD}}$ on pin Input Leakage Current 0.001 1 μΑ I_{LK} **PROG Input** Charge Impedance Range R_{PROG} 1 10 kΩ Shutdown Impedance 200 $k\Omega$ Impedance for Shutdown R_{PROG} PROG Voltage Range 0 5 ٧ V_{PROG}

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise indicated, all limits apply for V_{DD}= [V_{REG}(Typical) + 0.3V] to 12V, $T_A = -40$ °C to +85°C. Typical values are at +25°C, $V_{DD} = [V_{REG} \text{ (Typical)} + 1.0V]$ Sym. Min. Units **Parameters** Тур. Max. Conditions **Automatic Power Down** Automatic Power Down ٧ V_{BAT} + V_{DD} Falling V_{PDENTRY} V_{BAT} + 50 mV Entry Threshold 10 mV Automatic Power Down Exit V_{PDEXIT} V_{BAT} + V_{BAT} + V_{DD} Rising Threshold 250 mV 150 mV **Thermal Shutdown** T_{SD} Die Temperature 150 ٥С °С Die Temperature Hysteresis T_{SDHYS} 10

Note 1: Not production tested. Ensured by design.

AC CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, all limits apply for V_{DD} = [V_{REG} (Typical)+0.3V] to 6V, T_A =-40°C to +85°C. Typical values are at +25°C, V_{DD}= [V_{REG}(Typical)+1.0V] Units Conditions **Parameters** Sym. Min. Max. Тур. **Elapsed Timer** Timer Disabled **Elapsed Timer Period** 0 Hours t_{ELAPSED} 3.6 4.0 4.4 Hours 5.4 6.0 6.6 Hours 7.2 8.0 8.8 Hours **Preconditioning Timer** Preconditioning Timer Period **Disabled Timer** 0 Hours **t**PRECHG 0.5 0.6 0.4 Hours **Status Indicator** $I_{SINK} = 1 \text{ mA to } 0 \text{ mA}$ Status Output turn-off 500 μs toff (Note 1) $I_{SINK} = 0 \text{ mA to } 1 \text{ mA}$ 500 Status Output turn-on t_{ON} (Note 1)

Note 1: Not production tested. Ensured by design.

TEMPERATURE SPECIFICATIONS

Electrical Specifications: Unless other Typical values are at $+25^{\circ}$ C, $V_{DD} = [V_{RE}]$			apply for \	$V_{DD} = [V_{REG}]$	(Typical) +	0.3V] to 6V.
Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Specified Temperature Range	T _A	-40	_	+85	°C	
Operating Temperature Range	TJ	-40	_	+125	°C	
Storage Temperature Range	T _A	-65	_	+150	°C	
Thermal Package Resistances						
Thermal Resistance, DFN-10 (3x3)	θ_{JA}	_	64	_	°C/W	4-Layer JC51-7 Standard Board, Natural Convection
	θ_{JC}	_	12	_	°C/W	

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $V_{DD} = [V_{REG} (Typical) + 1V]$, $I_{OUT} = 50$ mA and $T_{A} = +25$ °C, Constant Voltage mode.

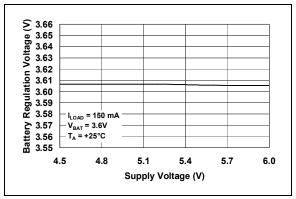


FIGURE 2-1: Battery Regulation Voltage (V_{BAT}) vs. Supply Voltage (V_{DD}) .

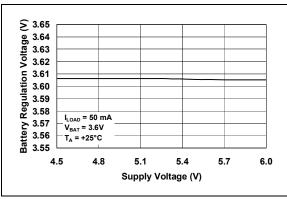


FIGURE 2-2: Battery Regulation Voltage (V_{BAT}) vs. Supply Voltage (V_{DD}) .

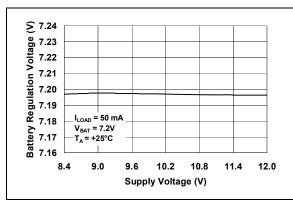


FIGURE 2-3: Battery Regulation Voltage (V_{BAT}) vs. Supply Voltage (V_{DD}) .

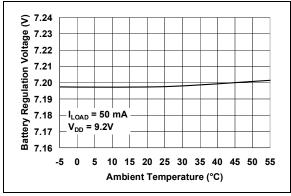


FIGURE 2-4: Battery Regulation Voltage (V_{BAT}) vs. Ambient Temperature (T_A) .

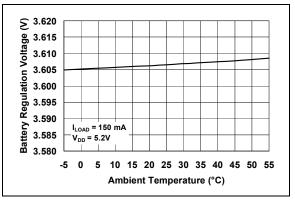


FIGURE 2-5: Battery Regulation Voltage (V_{BAT}) vs. Ambient Temperature (T_A) .

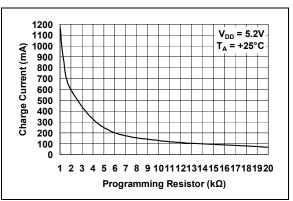


FIGURE 2-6: Charge Current (I_{OUT}) vs. Programming Resistor (R_{PROG}).

TYPICAL PERFORMANCE CURVES (CONTINUED)

Note: Unless otherwise indicated, $V_{DD} = [V_{REG} (Typical) + 1V]$, $I_{OUT} = 10$ mA and $T_A = +25$ °C, Constant Voltage mode.

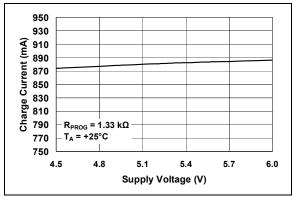


FIGURE 2-7: Charge Current (I_{OUT}) vs. Supply Voltage (V).

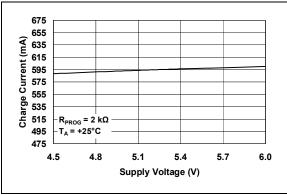


FIGURE 2-8: Charge Current (I_{OUT}) vs. Supply Voltage (V).

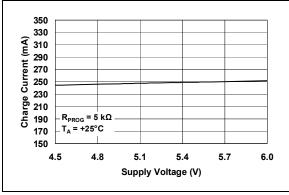


FIGURE 2-9: Charge Current (I_{OUT}) vs. Supply Voltage (V).

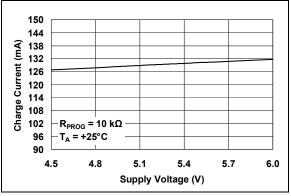


FIGURE 2-10: Charge Current (I_{OUT}) vs. Programming Resistor (R_{PROG}).

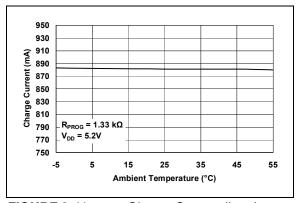


FIGURE 2-11: Charge Current (I_{OUT}) vs. Ambient Temperature (T_A).

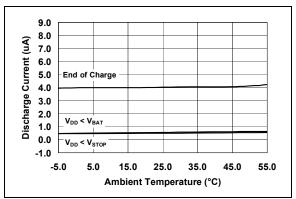


FIGURE 2-12: Output Leakage Current $(I_{DISCHARGE})$ vs. Ambient Temperature (T_A) .

TYPICAL PERFORMANCE CURVES (CONTINUED)

Note: Unless otherwise indicated, $V_{DD} = [V_{REG} (Typical) + 1V]$, $I_{OUT} = 10$ mA and $T_A = +25$ °C, Constant Voltage mode.

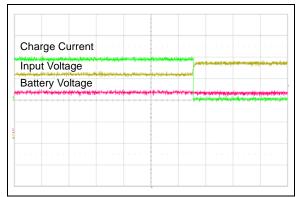


FIGURE 2-13: Overvoltage Protection Start (50 ms/Div).

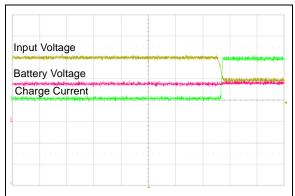


FIGURE 2-14: Overvoltage Protection Stop (50 ms/Div).

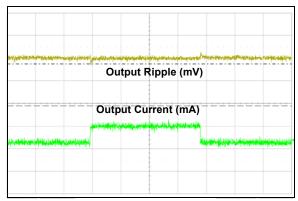


FIGURE 2-15: Load Transient Response $(I_{LOAD} = 50 \text{ mA}, \text{ Output Ripple: } 100 \text{ mV/Div}, \text{ Output Current: } 50 \text{ mA/Div}, \text{ Time: } 100 \text{ µs/Div}).$

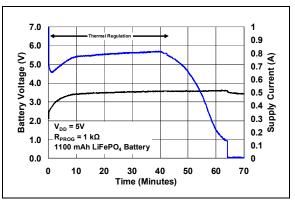


FIGURE 2-16: Complete Charge Cycle (1100 mAh LiFePO₄ Battery).

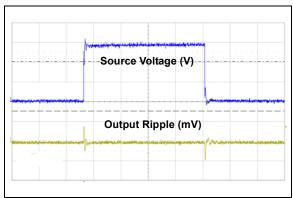


FIGURE 2-17: Line Transient Response $(I_{LOAD} = 10 \text{ mA}, \text{ Source Voltage: } 2V/\text{Div}, \text{ Output Ripple: } 100 \text{ mV/Div}, \text{ Time: } 100 \text{ µs/Div}).$

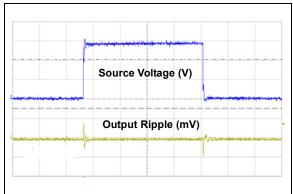


FIGURE 2-18: Line Transient Response (I_{LOAD} = 100 mA, Source Voltage: 2V/Div, Output Ripple: 100 mV/Div, Time: 100 μs/Div).

3.0 PIN DESCRIPTION

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

MCP73123/223	Symbol	I/O	Description
DFN-10	Symbol	"	Description
1, 2	V _{DD}	ı	Battery Management Input Supply
3, 4	V_{BAT}	I/O	Battery Charge Control Output
5, 6	NC	—	No Connection
7	STAT	0	Battery Charge Status Output
8, 9	V _{SS}	_	Battery Management 0V Reference
10	PROG	I/O	Battery Charge Current Regulation Program and Charge Control Enable
11	EP	_	Exposed Pad

3.1 Battery Management Input Supply (VDD)

A supply voltage of [V_{REG} (Typical) + 0.3V] to 6.0V is recommended for MCP73123, while a supply voltage of [V_{REG} (Typical) + 0.3V] to 12.0V is recommended for MCP73223. Bypass to V_{SS} with a minimum of 1 μ F. The V_{DD} pin is rated 18V absolute maximum to prevent sudden rise of input voltage from spikes or low cost AC-DC wall adapter.

3.2 Battery Charge Control Output (V_{RAT})

Connect to the positive terminal of the battery. Bypass to V_{SS} with a minimum of 1 μF to ensure loop stability when the battery is disconnected. The MCP73123 is designed to provide 3.6V battery regulation voltage for LiFePO₄ batteries. Undercharge may occur if a typical Li-lon or Li-Poly battery is used.

3.3 No Connect (NC)

No connect.

3.4 Status Output (STAT)

STAT is an open-drain logic output for connection to an LED for charge status indication in stand-alone applications. Alternatively, a pull-up resistor can be applied for interfacing to a host microcontroller. Refer to Table 5-1 for a summary of the status output during a charge cycle.

3.5 Battery Management 0V Reference (V_{SS})

Connect to the negative terminal of the battery and input supply.

3.6 Current Regulation Set (PROG)

The fast charge current is set by placing a resistor from PROG to V_{SS} during constant current (CC) mode.

The PROG pin also serves as a charge control enable pin. Allowing the PROG pin to float or connecting the pin to an impedance greater than 200 k Ω will disable the MCP73123/223 charger. Refer to **Section 5.5**, "Constant Current Mode – Fast Charge", for details.

3.7 Exposed Pad (EP)

The Exposed Thermal Pad (EP) shall be connected to the exposed copper area on the Printed Circuit Board (PCB) to enhance thermal power dissipation. Additional vias on the copper area under the MCP73123/223 device will improve the performance of heat dissipation and simplify the assembly process. Connecting EP to V_{SS} is recommended.

4.0 DEVICE OVERVIEW

The MCP73123/223 are simple, but fully integrated linear charge management controllers. Figure 4-1 depicts the operational flow algorithm.

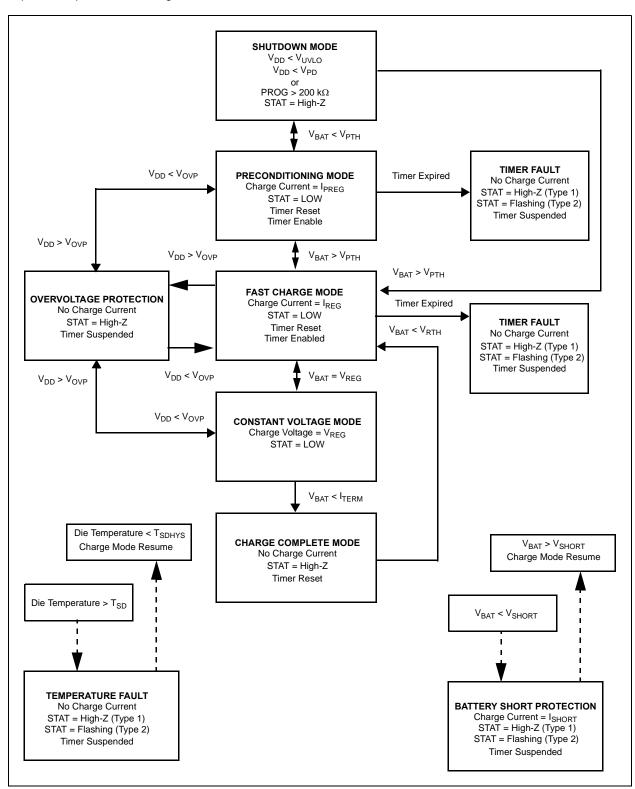


FIGURE 4-1: The MCP73123/223 Flow Chart.

5.0 DETAILED DESCRIPTION

5.1 Undervoltage Lockout (UVLO)

An internal undervoltage lockout (UVLO) circuit monitors the input voltage and keeps the charger in Shutdown mode until the input supply rises above the UVLO threshold. In the event a battery is present when the input power is applied, the input supply must rise approximately 150 mV above the battery voltage before the MCP73123/223 becomes operational.

The UVLO circuit places the device in Shutdown mode if the input supply falls to approximately 150 mV above the battery voltage. The UVLO circuit is always active. At any time, the input supply is below the UVLO threshold or approximately 150 mV of the voltage at the V_{BAT} pin, the MCP73123/223 device is placed in a Shutdown mode.

5.2 Overvoltage Protection (OVP)

An internal OVP circuit monitors the input voltage and keeps the charger in Shutdown mode when the input supply rises above the OVP threshold. The hysteresis of OVP is approximately 150 mV for the MCP73123/223 device.

The MCP73123/223 device is operational between UVLO and OVP threshold. The OVP circuit is also recognized as an overvoltage lockout (OVLO).

5.3 Charge Qualification

When the input power is applied, the input supply must rise 150 mV above the battery voltage before the MCP73123/223 becomes operational.

The automatic power down circuit places the device in Shutdown mode if the input supply falls to within +50 mV of the battery voltage.

The automatic circuit is always active. At any time the input supply is within +50 mV of the voltage at the V_{BAT} pin, the MCP73123/223 is placed in a Shutdown mode.

For a charge cycle to begin, the automatic power down conditions must be met and the charge enable input must be above the input high threshold.

Note:	In order	to ex	tend the	batte	ry cycle	life, the
	charge	will	initiate	only	when	battery
	voltage	is be	low 3.4V	per c	ell.	

5.3.1 BATTERY MANAGEMENT INPUT SUPPLY (V_{DD})

The V_{DD} input is the input supply to the MCP73123/223. The MCP73123/223 automatically enters a Power-down mode if the voltage on the V_{DD} input falls to within +50 mV of the battery voltage. This feature prevents draining the battery pack when the V_{DD} supply is not present.

5.3.2 BATTERY CHARGE CONTROL OUTPUT (V_{BAT})

The battery charge control output is the drain terminal of an internal P-channel MOSFET. The MCP73123/223 provides constant current and voltage regulation to the battery pack by controlling this MOSFET in the linear region. The battery charge control output should be connected to the positive terminal of the battery pack.

5.3.3 BATTERY DETECTION

The MCP73123/223 detects the battery presence by monitoring the voltage at V_{BAT} . The charge flow will initiate when the voltage on V_{BAT} is below the $V_{RECHARGE}$ threshold. Refer to the **Section 1.0**, **"Electrical Characteristics"**, for $V_{RECHARGE}$ values.

When $V_{BAT} > V_{REG} + Hysteresis$, the charge will be suspended or not started, depending on the current charge status, to prevent overcharging.

5.4 Preconditioning

If the voltage at the V_{BAT} pin is less than the preconditioning threshold, the MCP73123/223 device enters a Preconditioning mode. The preconditioning threshold is factory set. Refer to **Section 1.0**, **"Electrical Characteristics"**, for preconditioning threshold options.

In this mode, the MCP73123/223 device supplies 10% of the fast charge current (established with the value of the resistor connected to the PROG pin) to the battery.

When the voltage at the V_{BAT} pin rises above the preconditioning threshold, the MCP73123/223 device enters the Constant Current (Fast Charge) mode.

Note:	The MCP73123/223 also offers options
	with no preconditioning.

5.4.1 TIMER EXPIRED DURING PRECONDITIONING MODE

If the internal timer expires before the voltage threshold is reached for Fast Charge mode, a timer fault is indicated and the charge cycle terminates. The MCP73123/223 device remains in this condition until the battery is removed or input power is cycled. If the battery is removed, the MCP73123/223 device enters Standby mode, where it remains until a battery is reinserted.

Note:	The typical preconditioning timer for
	MCP73123/223 is 32 minutes. The
	MCP73123/223 also offers options with no
	preconditioning timer.

5.5 Constant Current Mode – Fast Charge

During the Constant Current mode, the programmed charge current is supplied to the battery or load.

The charge current is established using a single resistor from PROG to V_{SS} . The program resistor and the charge current are calculated using Equation 5-1 and Equation 5-2.

EQUATION 5-1:

 $I_{REG} = 1104 \times R^{-0.93}$

Where:

 $R_{PROG} = kilo-ohms (k\Omega)$ $I_{REG} = milliampere (mA)$

EQUATION 5-2:

 $R_{PROG} = 10^{(log(I_{REG}/1104)/(-0.93))}$

Where:

 $R_{PROG} = kilo-ohms (k\Omega)$ $I_{REG} = milliampere (mA)$

Table 5-1 provides commonly seen E96 (1%) and E24 (5%) resistors for various charge current to reduce design time.

TABLE 5-1: RESISTOR LOOKUP TABLE

Charge Current (mA)	Recommended E96 Resistor (Ω)	Recommended E24 Resistor (Ω)
130	10k	10k
150	8.45k	8.20k
200	6.20k	6.20k
250	4.99k	5.10k
300	4.02k	3.90k
350	3.40k	3.30k
400	3.00k	3.00k
450	2.61k	2.70k
500	2.32k	2.37k
550	2.10k	2.20k
600	1.91k	2.00k
650	1.78k	1.80k
700	1.62k	1.60k
750	1.50k	1.50k
800	1.40k	1.50k
850	1.33k	1.30k
900	1.24k	1.20k
950	1.18k	1.20k
1000	1.10k	1.10k
1100	1.00k	1.00k

Constant Current mode is maintained until the voltage at the V_{BAT} pin reaches the regulation voltage, V_{REG} . When Constant Current mode is invoked, the internal timer is reset.

5.5.1 TIMER EXPIRED DURING CONSTANT CURRENT – FAST CHARGE MODE

If the internal timer expires before the recharge voltage threshold is reached, a timer fault is indicated and the charge cycle terminates. The MCP73123/223 device remains in this condition until the battery is removed. If the battery is removed or input power is cycled, the MCP73123/223 device enters the Standby mode, where it remains until a battery is reinserted.

5.6 Constant Voltage Mode

When the voltage at the V_{BAT} pin reaches the regulation voltage, V_{REG} constant voltage regulation begins. The regulation voltage is factory set to 3.6V for a single cell, with a tolerance of $\pm 0.5\%$; or 7.2V for dual cells, with a tolerance of $\pm 0.6\%$.

5.7 Charge Termination

The charge cycle is terminated when, during Constant Voltage mode, the average charge current diminishes below a threshold established with the value of 5%, 7.5%, 10% or 20% of fast charge current or internal timer has expired. A 1 ms filter time on the termination comparator ensures that transient load conditions do not result in premature charge cycle termination. The timer period is factory set and can be disabled. Refer to **Section 1.0**, "**Electrical Characteristics**", for timer period options.

5.8 Automatic Recharge

The MCP73123/223 device continuously monitors the voltage at the V_{BAT} pin in the Charge Complete mode. If the voltage drops below the recharge threshold, another charge cycle begins and current is once again supplied to the battery or load. The recharge threshold is factory set. Refer to **Section 1.0**, "**Electrical Characteristics**", for recharge threshold options.

Note: The MCP73123/223 also offer options with no automatic recharge.

For the MCP73123/223 device with no recharge option, the MCP73123/223 will go into Standby mode when the termination condition is met. The charge will not restart until at least one of the following conditions have been met:

- The battery is removed from the system and inserted again
- $\bullet~$ V_{DD} is removed and plugged in again
- R_{PROG} is disconnected (or high impedance) and reconnected

5.9 Thermal Regulation

The MCP73123/223 limits the charge current, based on the die temperature. This thermal regulation optimizes the charge cycle time while maintaining device reliability. Figure 5-1 depicts the thermal regulation for the MCP73123/223 device. Refer to Section 1.0, "Electrical Characteristics", for thermal package resistances and Section 6.1.1.2 "Thermal Considerations", for calculating power dissipation.

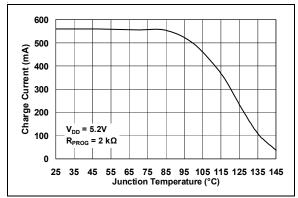


FIGURE 5-1: Thermal Regulation.

5.10 Thermal Shutdown

The MCP73123/223 suspends charge if the die temperature exceeds +150°C. Charging will be resumed when the die temperature has cooled by approximately 10°C. This thermal shutdown is a secondary safety feature in the event that there is a failure within the thermal regulation circuitry.

5.11 Status Indicator

The charge status outputs are open-drain outputs with two different states: Low (L) and High Impedance (High-Z). The charge status outputs can be used to illuminate LEDs. Optionally, the charge status outputs can be used as an interface to a host microcontroller. Table 5-2 summarizes the state of the status outputs during a charge cycle.

TABLE 5-2: STATUS OUTPUTS

CHARGE CYCLE STATE	STAT
Shutdown	High-Z
Standby	High-Z
Preconditioning	L
Constant Current Fast Charge	L
Constant Voltage	L
Charge Complete - Standby	High-Z
Temperature Fault	1.6 second 50% DC Flashing (Type 2) High-Z (Type 1)
Timer Fault	1.6 second 50% DC Flashing (Type 2) High-Z (Type 1)
Preconditioning Timer Fault	1.6 second 50% DC Flashing (Type 2) High-Z (Type 1)

5.12 Battery Short Circuit Protection

When a lithium iron phosphate battery is detected, an internal battery short circuit protection circuit starts monitoring the battery voltage. When V_{BAT} is below the typical 1.7V battery short circuit protection threshold voltage per cell, the charging behavior is postponed. A 25 mA (typical) detection current is supplied for recovering from the battery short circuit condition.

Preconditioning mode resumes when V_{BAT} rises above the battery short circuit protection threshold. The battery voltage must rise approximately 150 mV above the battery short circuit protection voltage before the MCP73123/223 device becomes operational.

6.0 APPLICATIONS

The MCP73123/223 is designed to operate with a host microcontroller or in stand-alone applications. The MCP73123/223 provides the preferred charge algorithm for lithium iron phosphate cells, Constant Current mode followed by Constant Voltage mode.

Figure 6-1 depicts a typical stand-alone application circuit, while Figure 6-2 depicts the accompanying charge profile.

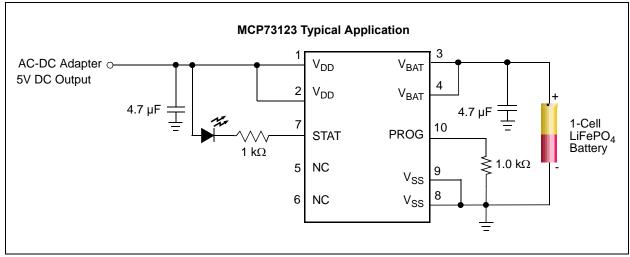


FIGURE 6-1: Typical Application Circuit.

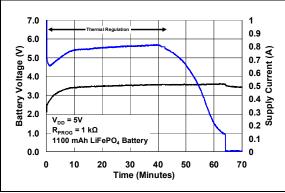


FIGURE 6-2: Typical Charge Profile for Single-Cell LiFePO₄ Battery.

6.1 Application Circuit Design

Due to the low efficiency of linear charging, the most important factors are thermal design and cost, which are a direct function of the input voltage, output current and thermal impedance between the battery charger and the ambient cooling air. The worst-case situation is when the device has transitioned from the Preconditioning mode to the Constant Current mode. In this situation, the battery charger has to dissipate the maximum power. A trade-off must be made between the charge current, cost, and thermal requirements of the charger.

6.1.1 COMPONENT SELECTION

Selection of the external components in Figure 6-1 is crucial to the integrity and reliability of the charging system. The following discussion is intended as a guide for the component selection process.

6.1.1.1 Charge Current

The recommended fast charge current should be obtained from the battery manufacturer. For example, a 1000 mAh battery pack with 2C preferred fast charge current has a charge current of 1000 mA. Charging at this rate provides the shortest charge cycle times without degradation of the battery pack performance or life.

Note:	Please consult with your battery supplier
	or refer to the battery data sheet for the
	preferred charge rate.

6.1.1.2 Thermal Considerations

The worst-case power dissipation in the battery charger occurs when the input voltage is at the maximum and the device has transitioned from the Preconditioning mode to the Constant Current mode. In this case, the power dissipation is calculated using Equation 6-1.

EQUATION 6-1:

 $PowerDissipation = (V_{DDMAX} - V_{PTHMIN}) \times I_{REGMAX}$ Where: $V_{DDMAX} = \text{ the maximum input voltage}$ $I_{REGMAX} = \text{ the maximum fast charge current}$ $V_{PTHMIN} = \text{ the minimum transition threshold}$

voltage

Power dissipation with a 5V, $\pm 10\%$ input voltage source, 500 mA $\pm 10\%$ and preconditioning threshold voltage at 2V is calculated using Equation 6-2.

EQUATION 6-2:

$$PowerDissipation = (5.5V - 2V) \times 550mA = 1.925W$$

This power dissipation with the battery charger in the DFN-10 package will raise the temperature approximately 83°C above room temperature.

6.1.1.3 External Capacitors

The MCP73123/223 is stable with or without a battery load. In order to maintain good AC stability in the Constant Voltage mode, a minimum capacitance of 1 μF is recommended to bypass the V_{BAT} pin to V_{SS} . This capacitance provides compensation when there is no battery load. In addition, the battery and interconnections appear inductive at high frequencies. These elements are in the control feedback loop during Constant Voltage mode. Therefore, the bypass capacitance may be necessary to compensate for the inductive nature of the battery pack.

A minimum of $1 \mu F$ is recommended for the output capacitor, and a minimum of $1 \mu F$ is recommended for the input capacitor in typical applications.

TABLE 6-1: MLCC CAPACITOR EXAMPLE

MLCC Capacitors	Temperature Range	Tolerance	
X7R	-55°C to +125°C	±15%	
X5R	-55°C to +85°C	±15%	

Virtually any good quality output filter capacitor can be used, independent of the capacitor's minimum Effective Series Resistance (ESR) value. The actual value of the capacitor (and its associated ESR) depends on the output load current. A 1 μF ceramic, tantalum, or aluminum electrolytic capacitor at the output is usually sufficient to ensure stability.

6.1.1.4 Reverse-Blocking Protection

The MCP73123/223 provides protection from a faulted or shorted input. Without the protection, a faulted or shorted input would discharge the battery pack through the body diode of the internal pass transistor.

6.2 PCB Layout Issues

For optimum voltage regulation, place the battery pack as close as possible to the device's V_{BAT} and V_{SS} pins to minimize voltage drops along the high-current-carrying PCB traces.

If the PCB layout is used as a heat sink, adding multiple vias in the heat sink pad can help conduct more heat to the backplane of the PCB, thus reducing the maximum junction temperature. Figure 6-3, Figure 6-4 and Figure 6-5 depict a typical layout with PCB heatsinking.

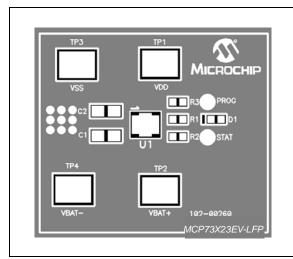


FIGURE 6-3: Typical Layout (Top).

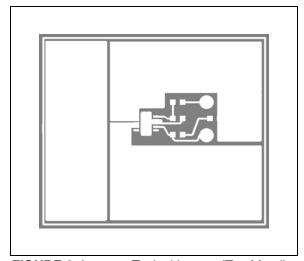


FIGURE 6-4: Typical Layout (Top Metal).

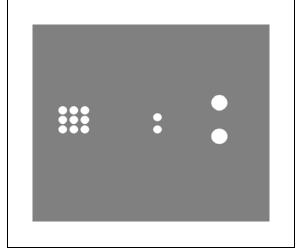


FIGURE 6-5: Typical Layout (Bottom).

7.0 PACKAGING INFORMATION

7.1 Package Marking Information

10-Lead DFN (3x3)

XXXX YYWW NNN

Standard *				
Part Number	Code			
MCP73123-22SI/MF	77HI			
MCP73223-C2SI/MF	X7HI			

Example:

77HI 1225 256

Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

Pb-free JEDEC designator for Matte Tin (Sn)

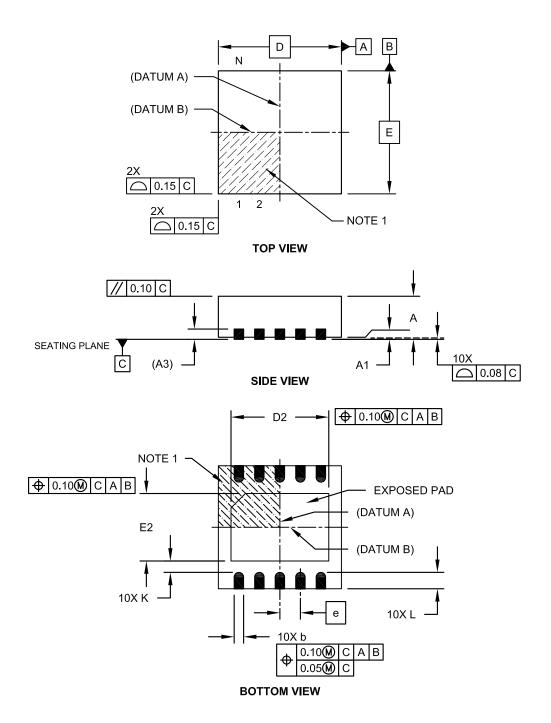
This package is Pb-free. The Pb-free JEDEC designator (e3)

can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

10-Lead Plastic Dual Flat, No Lead Package (MF) - 3x3x0.9mm Body [DFN]

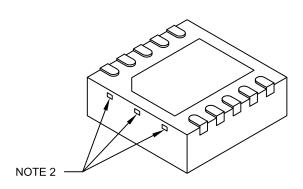
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-063C Sheet 1 of 2

10-Lead Plastic Dual Flat, No Lead Package (MF) - 3x3x0.9mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N	10		
Pitch	е	0.50 BSC		
Overall Height	Α	0.80	0.90	1.00
Standoff	A1	0.00	0.02	0.05
Contact Thickness			0.20 REF	
Overall Length	D	3.00 BSC		
Exposed Pad Length	D2	2.15	2.35	2.45
Overall Width	E	3.00 BSC		
Exposed Pad Width	E2	1.40	1.50	1.75
Contact Width	р	0.18	0.25	0.30
Contact Length	Ĺ	0.30	0.40	0.50
Contact-to-Exposed Pad	K	0.20	-	-

- Pin 1 visual index feature may vary, but must be located within the hatched area.
 Package may have one or more exposed tie bars at ends.
- 3. Package is saw singulated.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

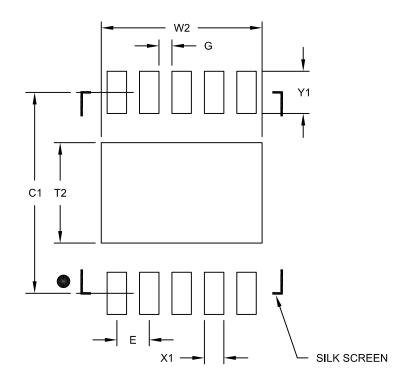
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-063C Sheet 2 of 2

10-Lead Plastic Dual Flat, No Lead Package (MF) - 3x3x0.9mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch E		0.50 BSC		
Optional Center Pad Width	W2			2.48
Optional Center Pad Length	T2			1.55
Contact Pad Spacing	C1		3.10	
Contact Pad Width (X10)	X1			0.30
Contact Pad Length (X10)	Y1			0.65
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2063B

MCP73123/223

NOTES:

APPENDIX A: REVISION HISTORY

Revision E (February 2013)

The following is the list of modifications:

- 1. Updated the Functional Block Diagram.
- 2. Updated the Temperature Specifications table.
- Updated Section 3.6 "Current Regulation Set (PROG)".
- 4. Updated Section 5.3.3 "Battery Detection".
- 5. Updated Equation 5-2.

Revision D (June 2011)

The following is the list of modifications:

 Updated the land pattern drawing of the 3x3 DFN package on page 27.

Revision C (January 2011)

The following is the list of modifications:

- 1. Added two more part numbers in Table 2.
- 2. Updated the flowchart in Figure 4-1.

Revision B (January 2010)

The following is the list of modifications:

- Updated the OVP value for MCP73223-C2S/MF in Table 2.
- Updated the Battery Short Protection values in the DC Characteristics table.

Revision A (July 2009)

· Original Release of this Document.

MCP73123/223

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip sales office.

PART NO. Device Te	X XX 	Examples: a) MCP73123-22SI/MF: Single Cell Lithium Iron Phosphate Battery Device b) MCP73123T-22SI/MF: Tape and Reel,
Device:	MCP73123: Single Cell Lithium Iron Phosphate Battery Device MCP73123T: Single Cell Lithium Iron Phosphate Battery Device, Tape and Reel MCP73223: Dual Cell Lithium Iron Phosphate Battery Device MCP73223T: Dual Cell Lithium Iron Phosphate Battery Device, Tape and Reel	a) MCP73223-C2SI/MF: Dual Cell Lithium Iron Phosphate Battery Device a) MCP73223-C2SI/MF: Dual Cell Lithium Iron Phosphate Battery Device a) MCP73223T-C2SI/MF: Tape and Reel, Dual Cell Lithium Iron Phosphate Battery Device
Temperature Range:	I = -40°C to +85°C (Industrial)	Consult your local Microchip sales office for alternative device options.
Package:	MF = Plastic Dual Flat No Lead, 3x3 mm Body (DFN), 10-Lead	

MCP73123/223

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the
 intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, KEELOQ, KEELOQ logo, MPLAB, PIC, PICmicro, PICSTART, PIC³² logo, rfPIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

FilterLab, Hampshire, HI-TECH C, Linear Active Thermistor, MTP, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

Analog-for-the-Digital Age, Application Maestro, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, HI-TIDE, In-Circuit Serial Programming, ICSP, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, mTouch, Omniscient Code Generation, PICC, PICC-18, PICDEM, PICDEM.net, PICkit, PICtail, REAL ICE, rfLAB, Select Mode, SQI, Serial Quad I/O, Total Endurance, TSHARC, UniWinDriver, WiperLock, ZENA and Z-Scale are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

GestIC and ULPP are registered trademarks of Microchip Technology Germany II GmbH & Co. & KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2009-2013, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

ISBN: 978-1-62076-998-0

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



Worldwide Sales and Service

AMERICAS

Corporate Office

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277

Technical Support: http://www.microchip.com/

support

Web Address: www.microchip.com

Atlanta

Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Cleveland

Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit

Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Indianapolis

Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

Santa Clara

Santa Clara, CA Tel: 408-961-6444 Fax: 408-961-6445

Toronto

Mississauga, Ontario,

Canada

Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office

Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong

Tel: 852-2401-1200 Fax: 852-2401-3431

Australia - Sydney Tel: 61-2-9868-6733

Fax: 61-2-9868-6755 China - Beijing

Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511

Fax: 86-28-8665-7889 China - Chongging

Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Hangzhou Tel: 86-571-2819-3187 Fax: 86-571-2819-3189

China - Hong Kong SAR

Tel: 852-2943-5100 Fax: 852-2401-3431

China - Nanjing Tel: 86-25-8473-2460

Fax: 86-25-8473-2470 China - Qingdao

Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

China - Shanghai Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen Tel: 86-755-8864-2200

Fax: 86-755-8203-1760 China - Wuhan

Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian

Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

China - Xiamen Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai Tel: 86-756-3210040 Fax: 86-756-3210049

ASIA/PACIFIC

India - Bangalore

Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi

Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune

Tel: 91-20-2566-1512 Fax: 91-20-2566-1513

Japan - Osaka Tel: 81-6-6152-7160

Fax: 81-6-6152-9310

Japan - Tokyo

Tel: 81-3-6880- 3770 Fax: 81-3-6880-3771

Korea - Daegu Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul

Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur

Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu

Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung Tel: 886-7-213-7828

Fax: 886-7-330-9305

Taiwan - Taipei Tel: 886-2-2508-8600

Fax: 886-2-2508-0102 Thailand - Bangkok

Tel: 66-2-694-1351 Fax: 66-2-694-1350

EUROPE

Austria - Wels

Tel: 43-7242-2244-39 Fax: 43-7242-2244-393 Denmark - Copenhagen

Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris

Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Munich

Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen Tel: 31-416-690399

Fax: 31-416-690340 Spain - Madrid

Tel: 34-91-708-08-90 Fax: 34-91-708-08-91 **UK - Wokingham**

Tel: 44-118-921-5869 Fax: 44-118-921-5820

11/29/12

ПОСТАВКА ЭЛЕКТРОННЫХ КОМПОНЕНТОВ

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г. Москва, ул. Щербаковская д. 3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru moschip.ru_6 moschip.ru_4 moschip.ru_9